140V PNP SILICON PLANAR MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -140V
- I_C = -4A high Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- Low saturation voltage $V_{CE(sat)}$ < -120mV @ I_C = -1A
- R_{SAT} = 92mΩ for a low equivalent On-Resistance
- h_{FE} specified up to -10A for a high gain hold up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

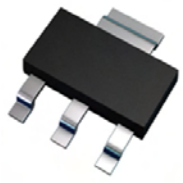
Mechanical Data

- Case: SOT223
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (approximate)

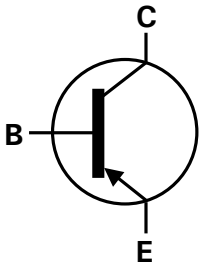
Application

- Motor driving
- Line switching
- High side switches
- Subscriber line interface cards (SLIC)

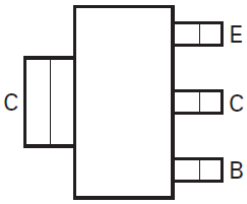
SOT223



Top View



Device Symbol



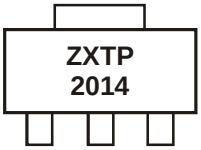
Top View
Pin-Out

Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2014GTA	ZXTP2014	7	12	1,000
ZXTP2014GTC	ZXTP2014	13	12	4,000

Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



ZXTP2014 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-180	V
Collector-Emitter Voltage	V_{CEO}	-140	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-4	A
Peak Pulse Current	I_{CM}	-10	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

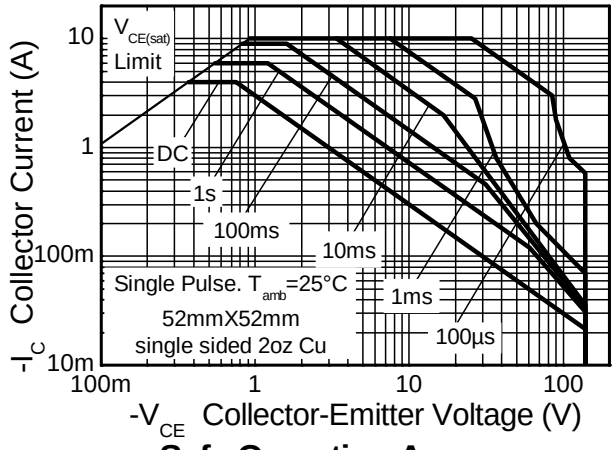
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5) Linear derating factor	P_D	3.0 24	W mW/°C
Power Dissipation (Note 6) Linear derating factor	P_D	1.6 12.8	W mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	42	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	78	°C/W
Thermal Resistance Junction to Lead (Note 7)	$R_{\theta JL}$	10.48	°C/W
Operating and Storage Temperature Range	T_J,T_{STG}	-55 to +150	°C

ESD Ratings (Note 8)

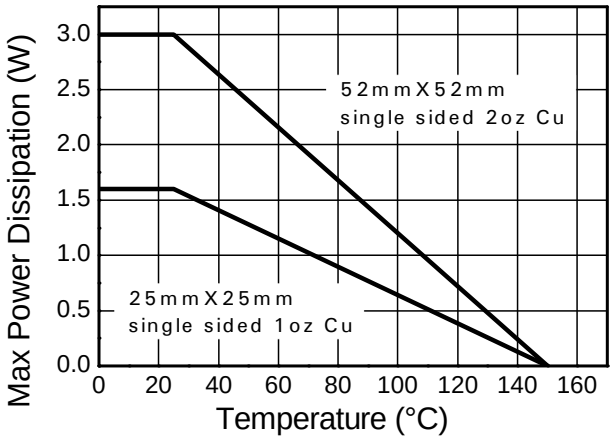
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

Notes:
5. For a device surface mounted on 52mm x 52mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
6. Same as note (5), except the device is surface mounted on 25mm x 25mm with 1oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

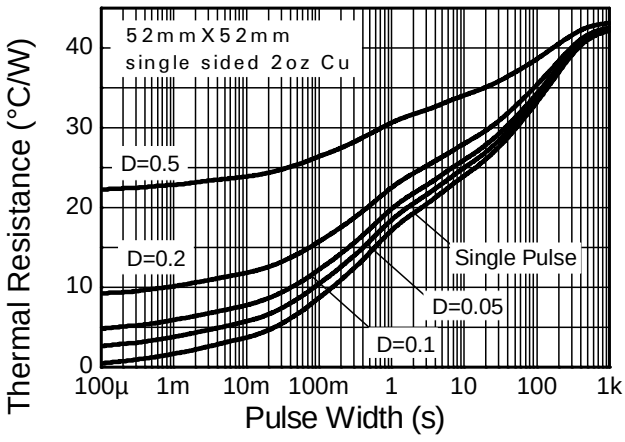
Thermal Characteristics and Derating Information



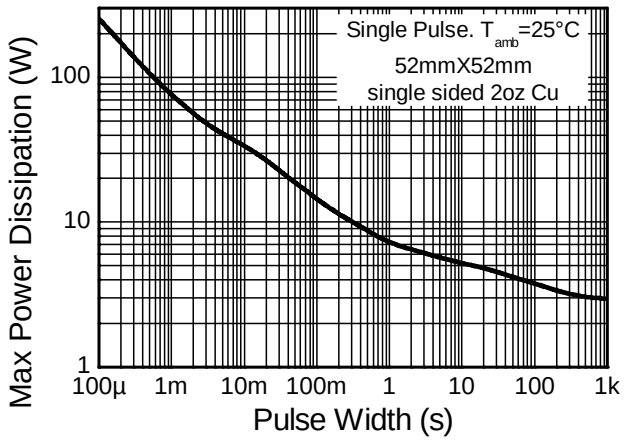
Safe Operating Area



Derating Curve



Transient Thermal Impedance



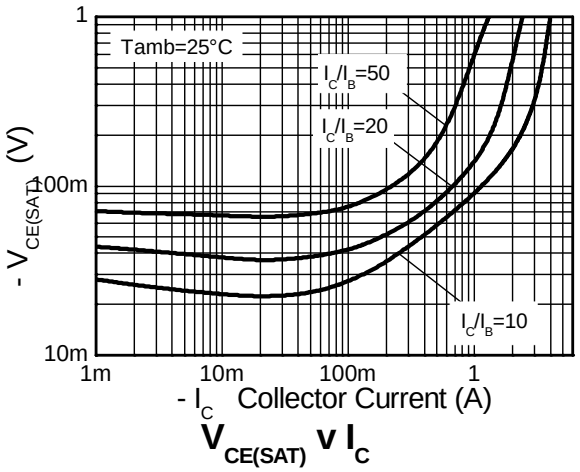
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

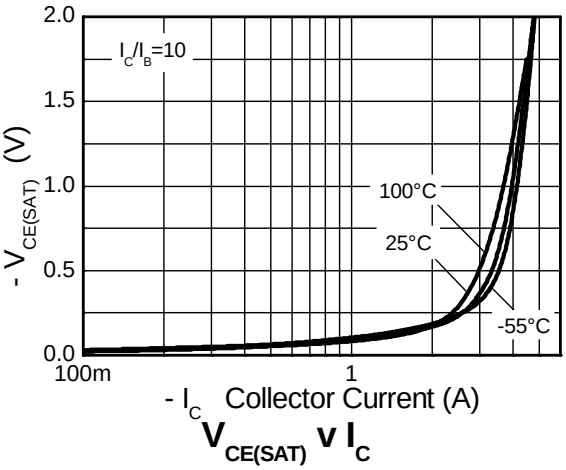
Characteristic	Symbol	Min	Typ.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-180	-200	-	V	I_C = -100µA
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CER}	-180	-200	-	V	I_C = -1µA, $R_B \leq 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-140	-160	-	V	I_C = -1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	-8.3	-	V	I_E = -100µA
Collector Cutoff Current	I_{CBO}	- -	< -1 -	-20 -500	nA nA	V_{CB} = -150V V_{CB} = -150V, T_A = +100°C
Collector Cutoff Current	I_{CER} R ≤1kΩ	- -	< -1 -	-20 -500	nA nA	V_{CB} = -150V V_{CB} = -150V, T_A = +100°C
Emitter Cutoff Current	I_{EBO}	-	< -1	-10	nA	V_{EB} = -6V
DC current transfer Static ratio (Note 9)	h_{FE}	100	225	-	-	I_C = -10mA, V_{CE} = -5V
		100	200	300		I_C = -1A, V_{CE} = -5V
		45	100	-		I_C = -3A, V_{CE} = -5V
		-	5	-		I_C = -10A, V_{CE} = -5V
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	-	-40	-60	mV	I_C = -100mA, I_B = -5mA
		-	-55	-80		I_C = -0.5A, I_B = -50mA
		-	-85	-120		I_C = -1A, I_B = -100mA
		-	-275	-360		I_C = -3A, I_B = -300mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	-940	-1040	mV	I_C = -3A, I_B = -300mA
Base-Emitter Turn-on Voltage (Note 9)	$V_{BE(on)}$	-	-830	-930	mV	I_C = -3A, V_{CE} = -5V
Transitional Frequency (Note 9)	f_T	-	120	-	MHz	I_C = -100mA, V_{CE} = -10V, f = 50MHz
Output capacitance	C_{obo}	-	33	-	pF	V_{CB} = -10V, f = 1MHz
Switching Time	t_{ON}	-	42	-	ns	V_{CC} = -50V, I_C = -1A, I_{B1} = -I_{B2} = -100mA
	t_{OFF}	-	636	-		

Notes: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

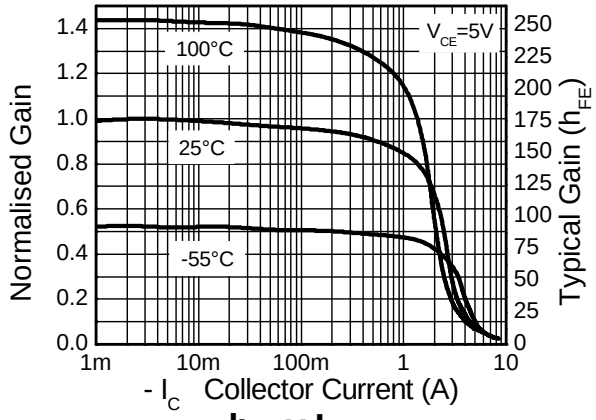
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



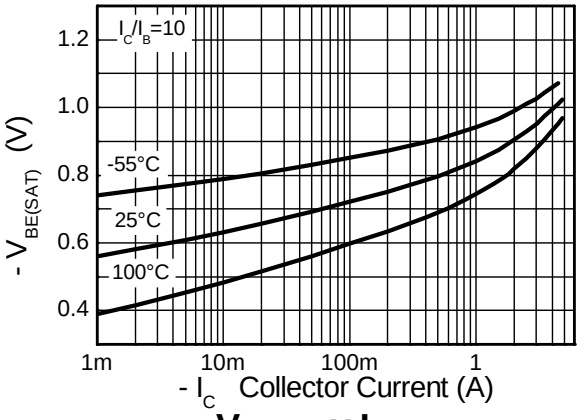
$V_{CE(SAT)}$ v I_C



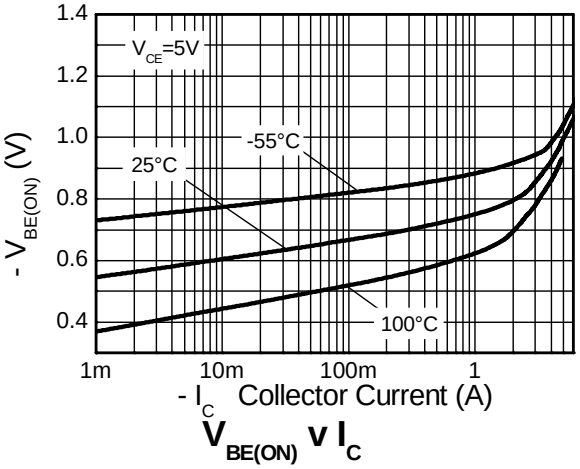
$V_{CE(SAT)}$ v I_C



h_{FE} v I_C



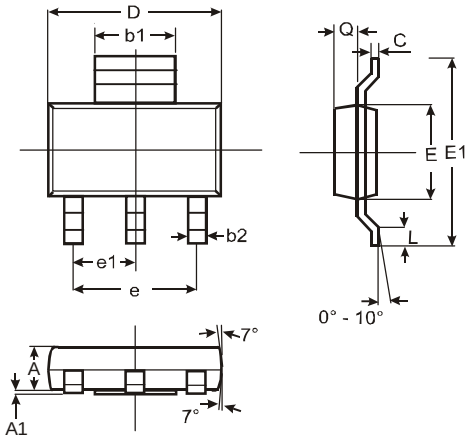
$V_{BE(SAT)}$ v I_C



$V_{BE(ON)}$ v I_C

Package Outline Dimensions

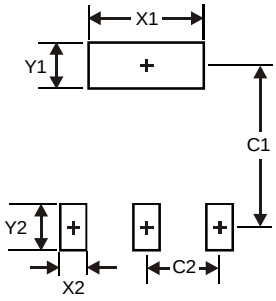
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b1	2.90	3.10	3.00
b2	0.60	0.80	0.70
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	—	—	4.60
e1	—	—	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X1	3.3
X2	1.2
Y1	1.6
Y2	1.6
C1	6.4
C2	2.3

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or

2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

www.diodes.com